



THE DATASHEET OF MAX6399ATA





High-Voltage, Overvoltage/Undervoltage, Protection Switch Controller

MAX6399

General Description

The MAX6399 is a small overvoltage and undervoltage protection circuit. The device can monitor a DC-DC output voltage and quickly disconnect the power source from the DC-DC input load when an overvoltage condition occurs. A power-OK output signals when the DC-DC input voltage falls below an adjustable threshold. This controller architecture provides the ability to size the external n-channel MOSFET to meet specific load current requirements.

When the DC-DC monitored output voltage is below the user-adjustable overvoltage threshold, the GATE output of the MAX6399 goes high to enhance the n-channel MOSFET. The MAX6399 offers internal charge-pump circuitry that allows the GATE voltage to be 10V above the input voltage ($V_{GS} = 10V$) to fully enhance the external n-channel MOSFET, thus minimizing the drain-to-source resistance.

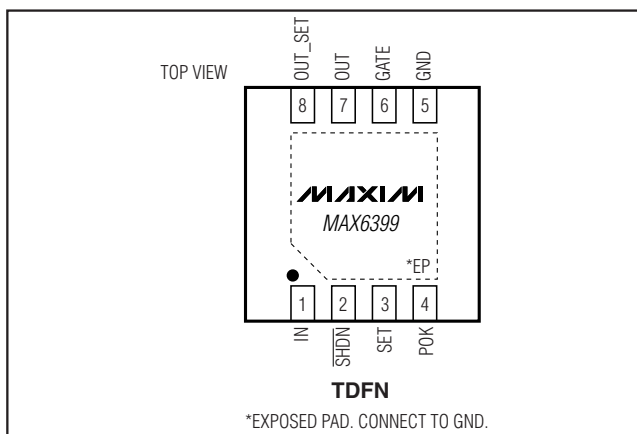
When the monitored output voltage rises above the user-adjusted overvoltage threshold, the GATE output rapidly pulls low to shut off the MOSFET. The MOSFET remains latched off until either the MAX6399 input power or SHDN input is cycled. The MAX6399 includes a logic-low shutdown input that disables the GATE. An internal overtemperature detector also disables the gate when the MAX6399 temperature reaches the thermal-shutdown threshold.

The device operates over a wide supply voltage range (5.75V to 72V) and is offered in a small TDFN package, fully specified from $-40^{\circ}C$ to $+125^{\circ}C$.

Applications

Networking Telecom
Server RAID

Pin Configuration



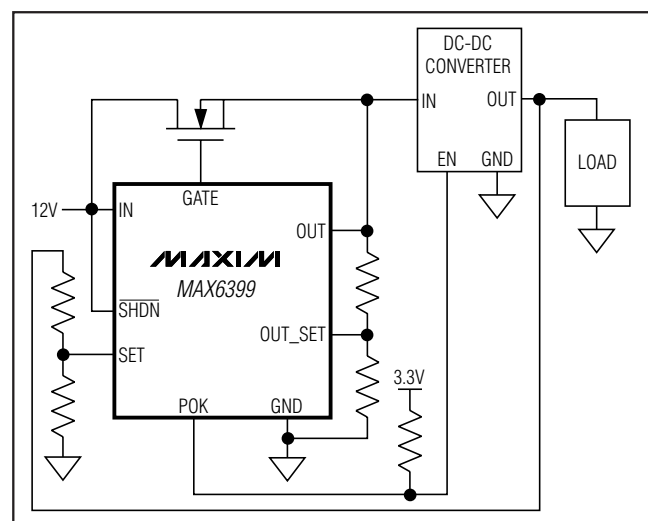
Features

- ◆ Wide Supply Voltage Range (5.75V to 72V)
- ◆ Internal Charge Pump Ensures n-Channel MOSFET is Fully Enhanced During Normal Operation ($V_{GS} = 10V$)
- ◆ Fast GATE Shutoff During Overvoltage with 20mA Sink Capability
- ◆ Latches Off External n-Channel MOSFET During High-Voltage Transients
- ◆ Adjustable DC-DC Input Undervoltage Threshold Power-OK Output
- ◆ Adjustable DC-DC Output Overvoltage Thresholds
- ◆ Overtemperature Shutdown Protection
- ◆ Fully Specified from $-40^{\circ}C$ to $+125^{\circ}C$

Ordering Information

PART	PIN-PACKAGE	TOP MARK	PKG CODE
MAX6399ATA-T	8 TDFN-8	ANE	T833-2

Typical Operating Circuit



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ABSOLUTE MAXIMUM RATINGS

IN, GATE, OUT	-0.3V to +80V
SHDN.....	-0.3V to (IN + 0.3V)
OUT	-0.3V to +80V
GATE to OUT.....	-0.3V to +20V
OUT_SET, SET, POK	-0.3V to +12V
Maximum Current (All pins)	50mA

Continuous Power Dissipation (T _A = +70°C)	
8-Pin TDFN (derate 18.2mW/°C above +70°C)	1455mW
Operating Temperature Range	-40°C to +125°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature Range.....	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{IN} = 14V; C_{GATE} = 6000pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage Range	V _{IN}		5.75		72.00	V
IN Supply Current	I _{IN}	SHDN = high		100	130	μA
		SHDN = low		10	22	
IN Undervoltage Lockout		V _{IN} rising, enables GATE	4.68	5	5.50	V
IN Undervoltage Lockout Hysteresis		V _{IN} falling, GATE off		155		mV
SET Threshold Voltage	V _{TH} (SET)	With respect to GND, SET rising	0.480	0.5	0.517	V
SET Threshold Hysteresis	V _{HYST}			5		% V _{TH}
SET Input Current	I _{SET}		-50		+50	nA
Startup Response Time	t _{START}	SHDN rising (Note 2)		100		μs
GATE Rise Time		GATE rising from GND to V _{OUT} + 8V, C _{GATE} = 6000pF, OUT = GND		1		ms
SET to GATE Prop Delay	t _{OV}	SET rising from V _{TH} - 100mV to V _{TH} + 100mV			0.5	μs
GATE Output-Voltage High	V _{OH}	V _{OUT} = V _{IN} = 5V, R _{GATE} to IN = 1MΩ	V _{IN} + 3.6V	V _{IN} + 3.8V	V _{IN} + 4.0V	V
		V _{OUT} = V _{IN} ; V _{IN} ≥ 14V, R _{GATE} to IN = 1MΩ	V _{IN} + 15V	V _{IN} + 10V	V _{IN} + 10.7V	
GATE Output-Voltage Low	V _{OL}	GATE sinking 20mA, V _{OUT_SET} = GND			0.3	V
GATE Charge-Pump Current	I _{GATE}	GATE = GND		75		μA
GATE to OUT Clamp Voltage	V _{CLMP}		13.8		18.0	V
SHDN Logic-High Input Voltage	V _{IH}		1.4			V
SHDN Logic-Low Input Voltage	V _{IL}				0.4	V
SHDN Input Pulldown Current		V _{SHDN} = 2V, SHDN is internally pulled down to GND		1		μA
Thermal-Shutdown Temperature (Note 3)				+150		°C
Thermal-Shutdown Hysteresis				20		°C
POWER-OK (POK)						
OUT_SET Threshold	V _{TH} (OUT_SET)	OUT_SET rising	1.205	1.23	1.258	V

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ELECTRICAL CHARACTERISTICS (continued)

($V_{IN} = 14V$; $C_{GATE} = 6000pF$, $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OUT_SET Hysteresis				5		% V_{TH} (OUT_SET)
OUT_SET to POK Delay		V_{OUT_SET} rising or falling		35		μs
POK Output Voltage Low	V_{OL}	$V_{IN} \geq 1.5V$, $I_{SINK} = 3.2mA$, POK asserted			0.45	V
POK Leakage Current		$V_{OUT_SET} = 1.4V$			100	nA

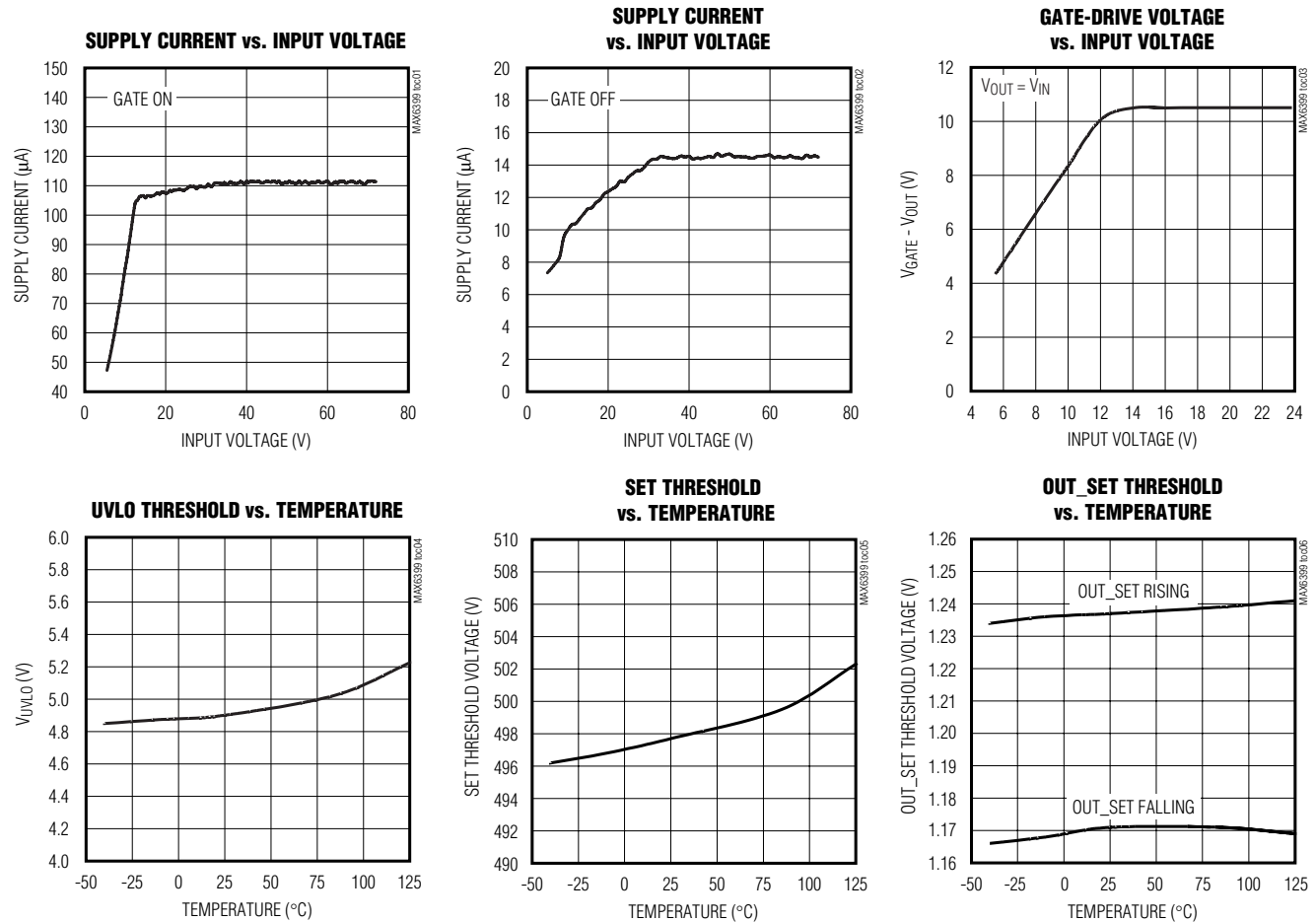
Note 1: Specifications to $-40^{\circ}C$ are guaranteed by design and not production tested.

Note 2: The MAX6399 powers up with the external FET in off mode ($V_{GATE} = GND$). The external FET turns on t_{START} after the device is powered up and all input conditions are valid.

Note 3: For accurate overtemperature shutdown performance, place the device in close thermal contact with the external MOSFET.

Typical Operating Characteristics

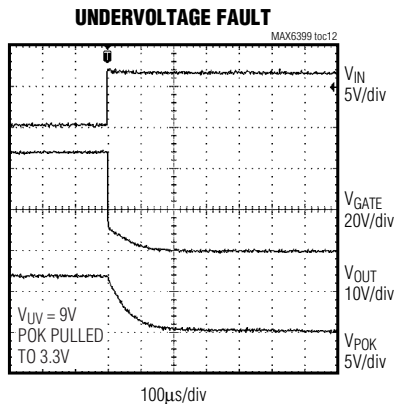
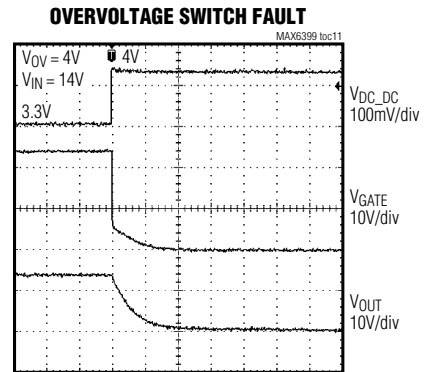
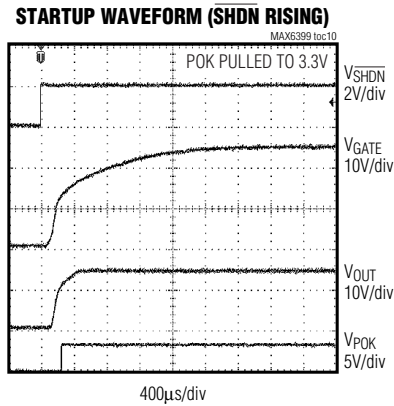
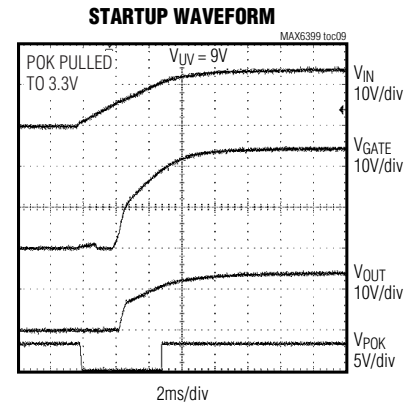
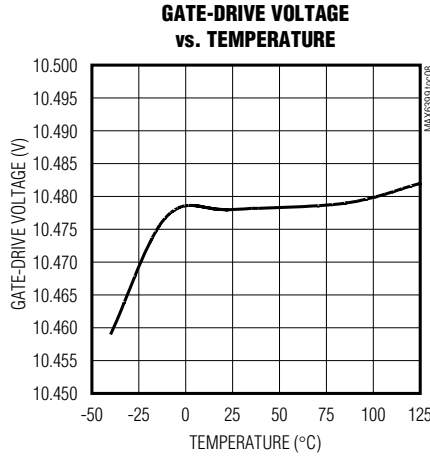
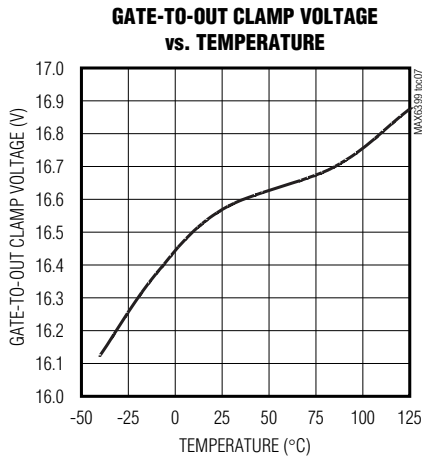
($V_{IN} = 14V$, $C_{GATE} = 6nF$, unless otherwise noted.)



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Typical Operating Characteristics (continued)

($V_{IN} = 14V$, $C_{GATE} = 6nF$, unless otherwise noted.)



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The MAX6399 includes internal thermal-shutdown protection, disabling the external MOSFET if the device reaches overtemperature conditions.

Shutdown Control

The MAX6399 active-low $\overline{\text{SHDN}}$ input turns off the external MOSFET, disconnecting the load and reducing power consumption. After power is applied and $\overline{\text{SHDN}}$ is driven above its logic-high voltage, there is a 100 μs delay before GATE begins to enhance. $\overline{\text{SHDN}}$ is also utilized to unlatch GATE after an overvoltage condition has been removed.

GATE Voltage

The MAX6399 uses a high-efficiency charge pump to generate the GATE voltage. Upon V_{IN} exceeding the 5V (typ) UVLO threshold, GATE enhances 10V above IN (for $V_{\text{IN}} \geq 14\text{V}$) with a 100 μA pullup current. An overvoltage condition occurs when the voltage at SET above its 0.5V threshold. When the overvoltage fault occurs ($\text{SET} = 0.5\text{V}$), GATE latches off, which disconnects the load from the power source (see Figure 2). After the overvoltage fault has disappeared, the fault can be unlatched by toggling $\overline{\text{SHDN}}$ or recycling the MAX6399 input.

DC-DC Output Overvoltage Protection

The MAX6399 overvoltage protection features a fast comparator that disconnects the load from the main power line when an overvoltage condition occurs at the output of a DC-DC converter. When an overvoltage condition is sensed, the MAX6399 latches GATE off, disconnecting the power source from the DC-DC input. To unlatch GATE after an overvoltage fault has disappeared, recycle IN or toggle $\overline{\text{SHDN}}$.

Setting Output Overvoltage Threshold (SET)

SET provides an accurate means of monitoring a system voltage for an overvoltage fault. Use a resistor-divider network to set the desired overvoltage condition (Figure 2). SET has a rising 0.5V threshold.

Begin by selecting the total end-to-end resistance, $R_{\text{TOTAL}} = R_1 + R_2$. Choose R_{TOTAL} to yield a total current equivalent to a minimum $100 \times I_{\text{SET}}$ (SET's input bias current) at the desired overvoltage threshold.

For example, with an overvoltage threshold set to 1.8V: $R_{\text{TOTAL}} < 1.8\text{V}/(100 \times I_{\text{SET}})$, where I_{SET} is SET's 50nA input bias current.

$$R_{\text{TOTAL}} < 360\text{k}\Omega$$

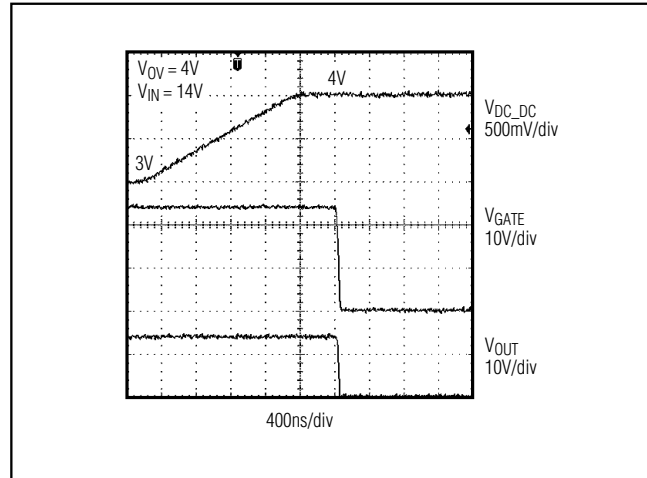


Figure 2. GATE Timing Diagram

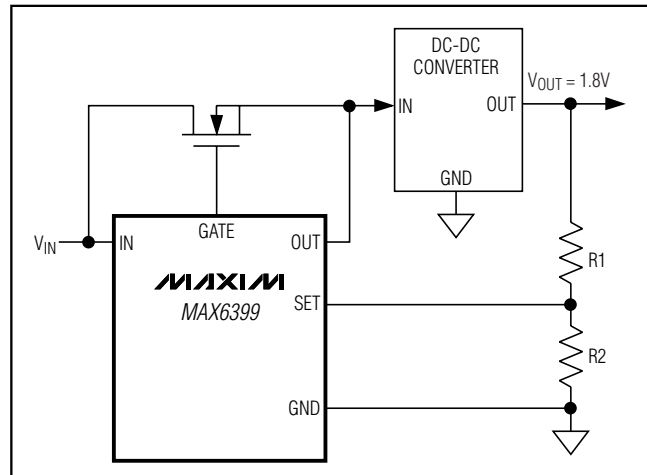


Figure 3. Output Overvoltage Protection Configuration

Use the following formula to calculate R2:

$$R_2 = V_{\text{TH}} \times \frac{R_{\text{TOTAL}}}{V_{\text{OV}}}$$

where V_{TH} is the 0.5V SET rising threshold and V_{OV} is the overvoltage condition at the output of a DC-DC converter, $R_2 = 100\text{k}\Omega$, $R_{\text{TOTAL}} = R_2 + R_1$, where $R_1 = 260\text{k}\Omega$. Use a 261k Ω standard resistor.

Using a lower value for total resistance dissipates more power but provides slightly better accuracy.

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Monitoring for DC-DC Input Undervoltage Conditions

The MAX6399 can be used to monitor for an undervoltage condition at the input of a DC-DC converter or another system voltage by connecting an external resistor-divider at OUT_SET (Figure 4). Use the following formula to calculate the undervoltage threshold (V_{UV}).

Begin by selecting the total end-to-end resistance, $R_{TOTAL} = R1 + R2$. Choose R_{TOTAL} to yield a total current equivalent to a minimum $100 \times I_{SET}$ (SET's input bias current) at the desired overvoltage threshold.

For example, with an undervoltage threshold set to 9V: $R_{TOTAL} < 9V / (100 \times I_{SET})$, where I_{SET} is SET's 50nA input bias current.

$$R_{TOTAL} < 1.8M\Omega$$

Use the following formula to calculate R2:

$$R2 = V_{TH(OUT_SET)} \times \frac{R_{TOTAL}}{V_{UV}}$$

where $V_{TH(OUT_SET)}$ is the 1.23V OUT_SET rising threshold and V_{UV} is the undervoltage condition at the input of a DC-DC converter.

$R2 = 246k\Omega$, $R_{TOTAL} = R2 + R1$, where $R1 = 1.554M\Omega$. Use a 1.54M Ω standard resistor.

Using a lower value for total resistance dissipates more power but provides slightly better accuracy.

Power-OK (POK) Output

POK is an open-drain output that goes low when OUT_SET falls below its 1.23V (typ) threshold voltage. Connect a pullup resistor from POK to a supply voltage. POK asserts high when OUT_SET ramps above 1.23V typical threshold. POK provides a valid output level down to $V_{IN} = 1.5V$.

Applications Information

Inrush/Slew-Rate Control

Inrush current control can be implemented by placing a capacitor at GATE (Figure 5) to slowly ramp up the GATE, thus limiting the inrush current and controlling GATE's slew rate during initial turn-on. The inrush current can be approximated using the following formula:

$$I_{INRUSH} = \frac{C_{OUT}}{C_{GATE}} \times I_{GATE} + I_{LOAD}$$

where I_{GATE} is GATE's 100 μ A sourcing current, I_{LOAD} is the load current at the DC-DC output at startup and C_{OUT} is the output's capacitor. However, most DC-DC converters have soft-start (or peak current limiting) functions that control inrush current.

Input Overvoltage Protection

The MAX6399 also allows overvoltage protection at the input supply (see Figure 6). When the programmed overvoltage threshold is tripped, the internal fast comparator turns off the external MOSFET, latching GATE and OUT low within t_{OVL} disconnecting the power source from the load. To unlatch the MAX6399 after an overvoltage fault, recycle IN or toggle \overline{SHDN} .

Input Transients Clamping

During hot plug-in/unplug, stray inductance in the power path may cause voltage ringing above the normal input DC value, which may exceed the MAX6399's 80V maximum supply rating. An input transient such as that caused by lightning can also put a severe transient peak voltage on the input rail. The following techniques are recommended to reduce the effect of transients:

- Minimize stray inductance in the power path using wide traces, and minimize loop area including the power traces and the return ground path.
- Add a zener diode or transient voltage suppressor (TVS) rated below the IN absolute maximum rating (Figure 7).
- Add a resistor in series with IN to limit transient current going into the input.

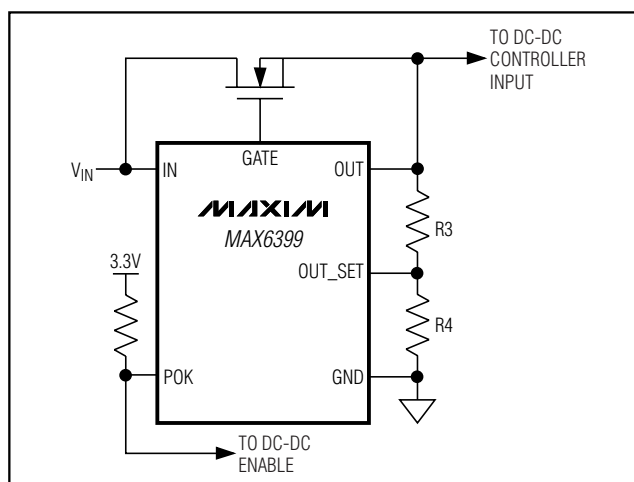


Figure 4. Setting the Undervoltage Threshold

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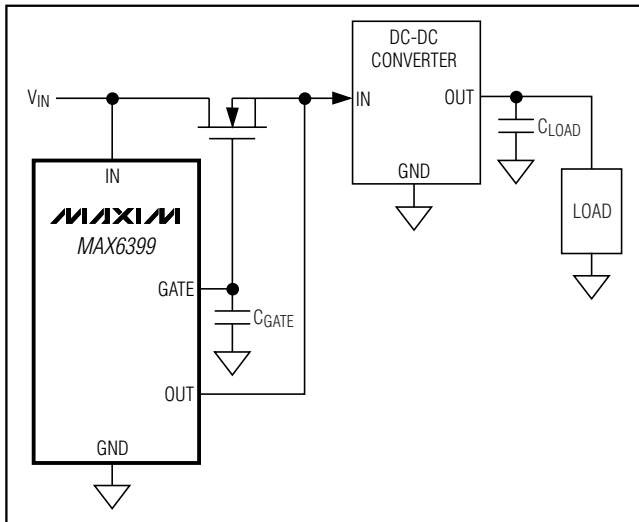


Figure 5. The MAX6399 Controlling GATE Inrush Current

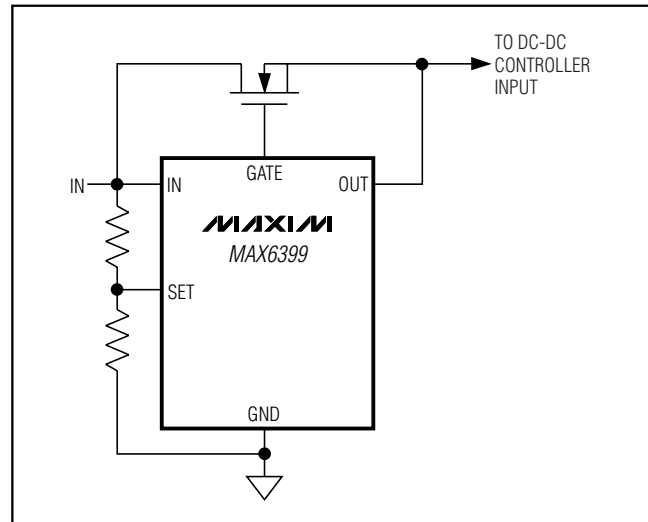


Figure 6. Input Overvoltage Protection Configuration

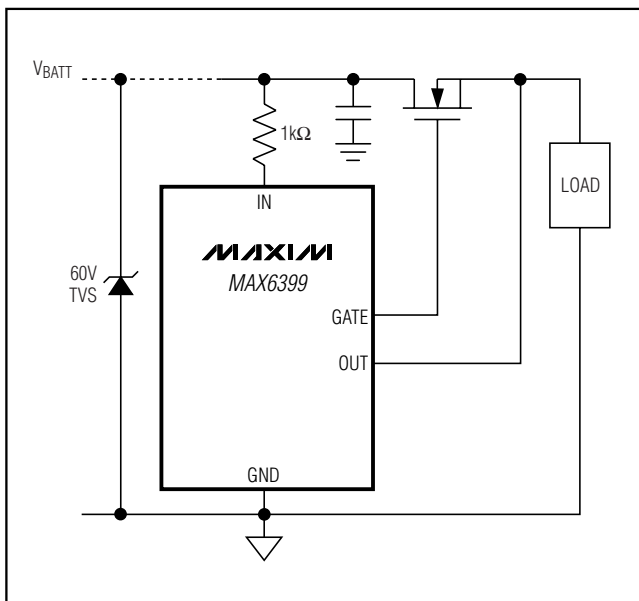


Figure 7. Protecting the MAX6399 Input from High-Voltage Transients

Reverse Voltage Protection

Use a diode or p-channel MOSFET to protect the MAX6399 during a reverse voltage insertion (Figures 8a, 8b). Low p-channel MOSFET on-resistance of $30\text{m}\Omega$ or less yields a forward-voltage drop of only a few millivolts (versus hundreds of millivolts for a diode, Figure 8a) thus improving efficiency in battery-operated devices.

Connecting a positive battery voltage to the drain of Q1 (Figure 8b) produces forward bias in its body diode, which clamps the source voltage one diode drop below the drain voltage. When the source voltage exceeds Q1's threshold voltage, Q1 turns on. Once the FET is on, the battery is fully connected to the system and can deliver power to the device and the load.

An incorrectly inserted battery reverse-biases the FET's body diode. The gate remains at the ground potential. The FET remains off and disconnects the reversed battery from the system. The zener diode and resistor combination prevent damage to the p-channel MOSFET during an overvoltage condition.

Thermal Shutdown

The MAX6399 thermal-shutdown feature monitors the PC board temperature of the external MOSFET when the devices sit on the same thermal island. Good thermal contact between the MAX6399 and the external n-channel MOSFET is essential for the thermal-shutdown feature to effectively operate. Place the n-channel MOSFET as close as possible to OUT.

When the MAX6399 junction temperature exceeds $T_J = +150^\circ\text{C}$, the thermal sensor signals the shutdown logic, turning off the GATE output, allowing the device to cool. The thermal sensor turns GATE on after the IC's junction temperature cools by 20°C . For continuous operation, do not exceed the absolute maximum junction-temperature rating of $T_J = +160^\circ\text{C}$.

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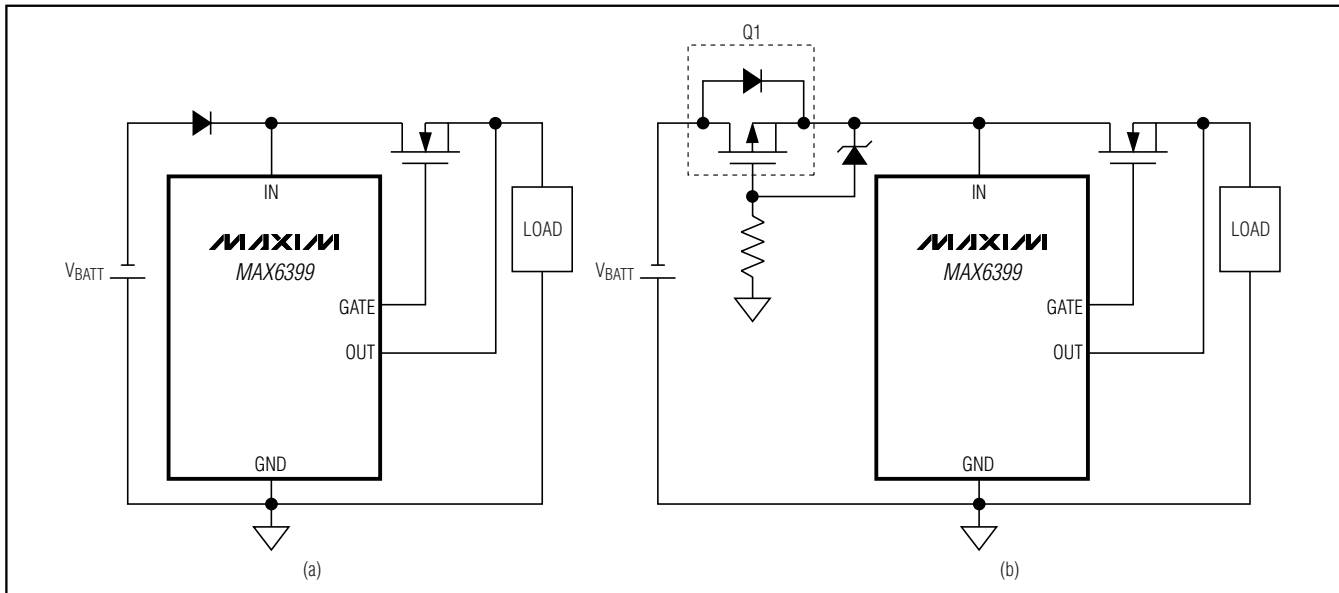


Figure 8. Reverse Voltage Protection Using a Diode or p-Channel MOSFET

MOSFET Selection

Select external MOSFETs according to the application current level. The MOSFETs on-resistance ($R_{DS(ON)}$) should be chosen low enough to have minimum voltage drop at full load to limit the MOSFET power dissipation.

Chip Information

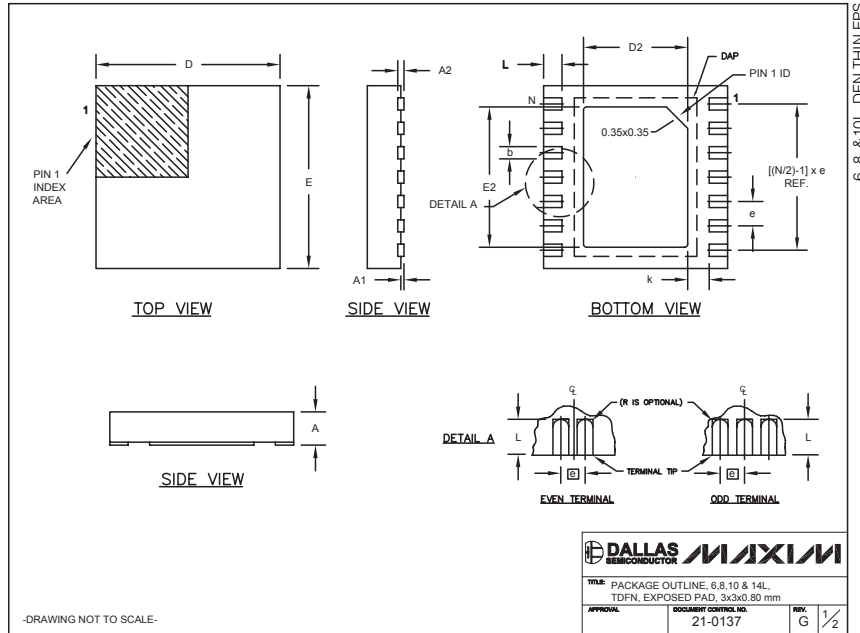
TRANSISTOR COUNT: 590

PROCESS: BiCMOS

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Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



COMMON DIMENSIONS									
SYMBOL	MIN.	MAX.							
A	0.70	0.80							
D	2.90	3.10							
E	2.90	3.10							
A1	0.00	0.05							
L	0.20	0.40							
k	0.25 MIN.								
A2	0.20 REF.								

PACKAGE VARIATIONS									
PKG. CODE	N	D2	E2	e	JEDEC SPEC	b	[(N/2)-1] x e	DOWNBONDS ALLOWED	
T633-1	6	1.50±0.10	2.30±0.10	0.95 BSC	MO229 / WEEA	0.40±0.05	1.90 REF	NO	
T633-2	6	1.50±0.10	2.30±0.10	0.95 BSC	MO229 / WEEA	0.40±0.05	1.90 REF	NO	
T833-1	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF	NO	
T833-2	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF	NO	
T833-3	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF	YES	
T1033-1	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF	NO	
T1433-1	14	1.70±0.10	2.30±0.10	0.40 BSC	----	0.20±0.05	2.40 REF	YES	
T1433-2	14	1.70±0.10	2.30±0.10	0.40 BSC	----	0.20±0.05	2.40 REF	NO	

NOTES:
 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
 2. COPLANARITY SHALL NOT EXCEED 0.08 mm.
 3. WARPAGE SHALL NOT EXCEED 0.10 mm.
 4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS SPECIAL CHARACTERISTIC(S).
 5. DRAWING CONFORMS TO JEDEC MO229, EXCEPT DIMENSIONS "D2" AND "E2", AND T1433-1 & T1433-2.
 6. "N" IS THE TOTAL NUMBER OF LEADS.
 7. NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY.

-DRAWING NOT TO SCALE-

<small>TITLE: PACKAGE OUTLINE, 6, 8, 10 & 14L, TDFN, EXPOSED PAD, 3x3x0.80 mm</small>	
<small>APPROVAL:</small>	<small>DOCUMENT CONTROL NO.:</small> 21-0137
	<small>REV.:</small> G 2/2

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